

MOSFET – Power, Dual, N-Channel, For 1-2 Cells Lithium-ion Battery Protection

24 V, 11.6 mΩ, 10 A,

ECH8697R

Description

This Power MOSFET features a low on-state resistance. This device is suitable for applications such as power switches of portable machines. Best suited for 1–2 cells Lithium–ion Battery applications.

Features

- Low On–Resistance
- 2.5 V Drive
- Common–Drain Type
- ESD Diode–Protected Gate
- Built–in Gate Protection Resistor
- These Devices are Pb–Free and are RoHS Compliant

Typical Applications

- 1–2 cells Lithium–ion Battery Charging and Discharging Switch

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

Symbol	Parameter	Value	Unit
V _{DSS}	Drain to Source Voltage	24	V
V _{GSS}	Gate to Source Voltage	±12.5	V
I _D	Drain Current (DC)	10	A
I _{DP}	Drain Current (Pulse) PW ≤ 10 μs, duty cycle ≤ 1%	60	A
P _D	Power Dissipation Surface mounted on ceramic substrate (1000 mm ² x 0.8 mm) 1 unit	1.5	W
P _T	Total Dissipation Surface mounted on ceramic substrate (1000 mm ² x 0.8 mm)	1.6	W
T _J	Junction Temperature	150	°C
T _{stg}	Storage Temperature	–55 to +150	°C

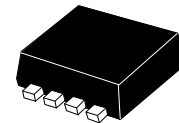
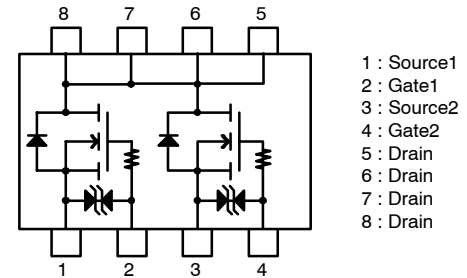
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
R _{θJA}	Junction to Ambient Surface mounted on ceramic substrate (1000 mm ² x 0.8 mm) 1 unit	83.3	°C/W

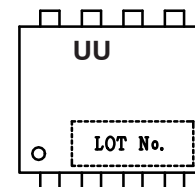
V _{DSS}	R _{DS(on)} Max	I _D Max
24 V	11.6 mΩ @ 4.5 V	10 A
	12.6 mΩ @ 4.0 V	
	15 mΩ @ 3.1 V	
	17.5 mΩ @ 2.5 V	

ELECTRICAL CONNECTION N–Channel



SOT–28FL/ECH8
CASE 318BF

MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

Symbol	Parameter	Conditions	Value			Unit
			Min	Typ	Max	
$V_{(BR)DSS}$	Drain to Source Breakdown Voltage	$I_D = 1 \text{ mA}$, $V_{GS} = 0 \text{ V}$	24	–	–	V
I_{DSS}	Zero-Gate Voltage Drain Current	$V_{DS} = 20 \text{ V}$, $V_{GS} = 0 \text{ V}$	–	–	1	μA
I_{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 8 \text{ V}$, $V_{DS} = 0 \text{ V}$	–	–	± 1	μA
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$	0.5	–	1.3	V
g_{FS}	Forward Transconductance	$V_{DS} = 10 \text{ V}$, $I_D = 5 \text{ A}$	–	5.0	–	S
$R_{DS(on)}$	Static Drain to Source On-State Resistance	$I_D = 5 \text{ A}$, $V_{GS} = 4.5 \text{ V}$	7.4	9.3	11.6	$\text{m}\Omega$
		$I_D = 5 \text{ A}$, $V_{GS} = 4.0 \text{ V}$	7.7	9.7	12.6	$\text{m}\Omega$
		$I_D = 5 \text{ A}$, $V_{GS} = 3.1 \text{ V}$	8.5	10.7	15	$\text{m}\Omega$
		$I_D = 2.5 \text{ A}$, $V_{GS} = 2.5 \text{ V}$	10	12.5	17.5	$\text{m}\Omega$
$t_{d(on)}$	Turn-ON Delay Time	See Figure 1 (Note 1)	–	160	–	ns
t_r	Rise Time		–	230	–	ns
$t_{d(off)}$	Turn-OFF Delay Time		–	19.7	–	μs
t_f	Fall Time		–	23.6	–	μs
$t_{d(on)}$	Turn-ON Delay Time	See Figure 2 (Note 1)	–	160	–	ns
t_r	Rise Time		–	230	–	ns
$t_{d(off)}$	Turn-OFF Delay Time		–	980	–	μs
t_f	Fall Time		–	350	–	μs
Q_g	Total Gate Charge	$V_{DS} = 10 \text{ V}$, $V_{GS} = 4.5 \text{ V}$, $I_D = 10 \text{ A}$	–	6	–	nC
Q_{gs}	Gate to Source Charge		–	1.1	–	nC
Q_{gd}	Gate to Drain “Miller” Charge		–	0.9	–	nC
V_{SD}	Forward Diode Voltage	$I_S = 10 \text{ A}$, $V_{GS} = 0 \text{ V}$	–	0.8	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. The fall switching time is dependent on the input pulse width.

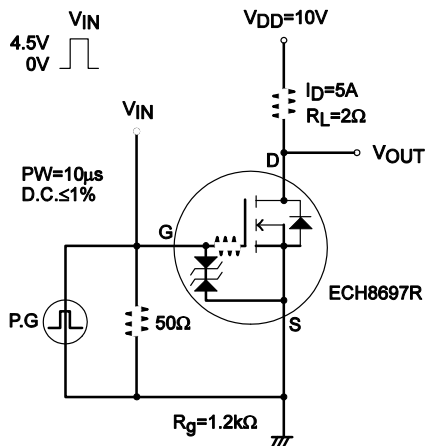


Figure 1. Switching Time Test Circuit 1

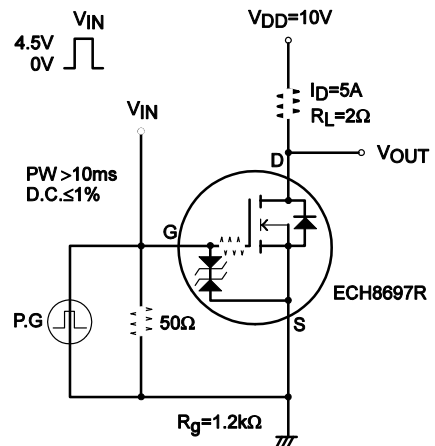


Figure 2. Switching Time Test Circuit 2

TYPICAL CHARACTERISTICS

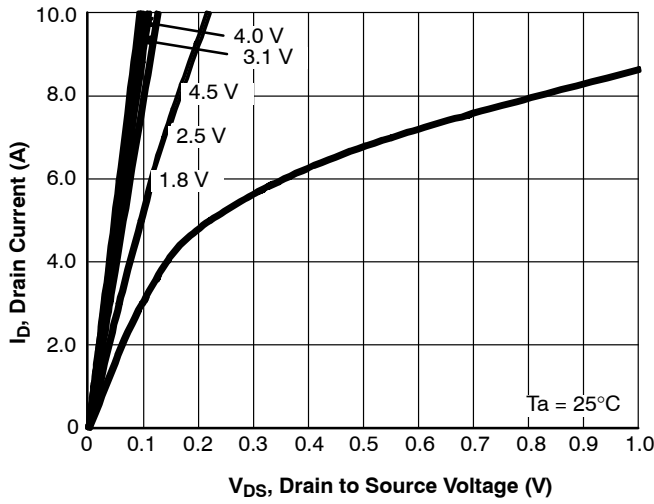


Figure 3. $I_D - V_{DS}$

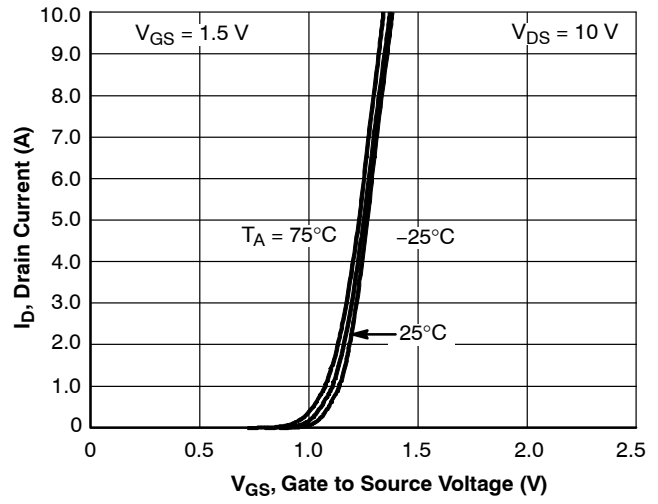


Figure 4. $I_D - V_{GS}$

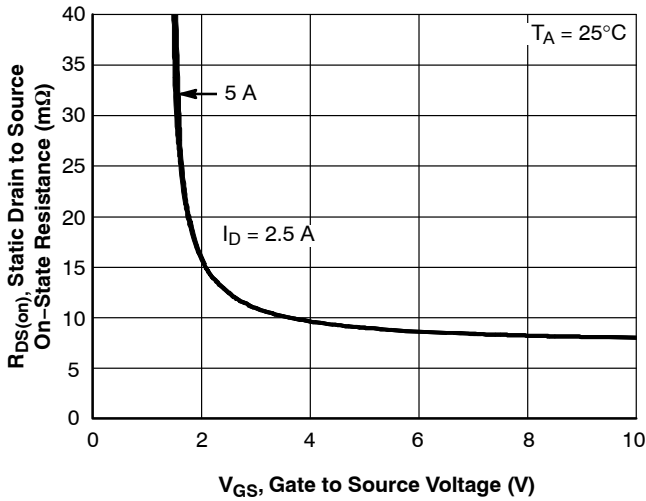


Figure 5. $R_{DS(on)} - V_{GS}$

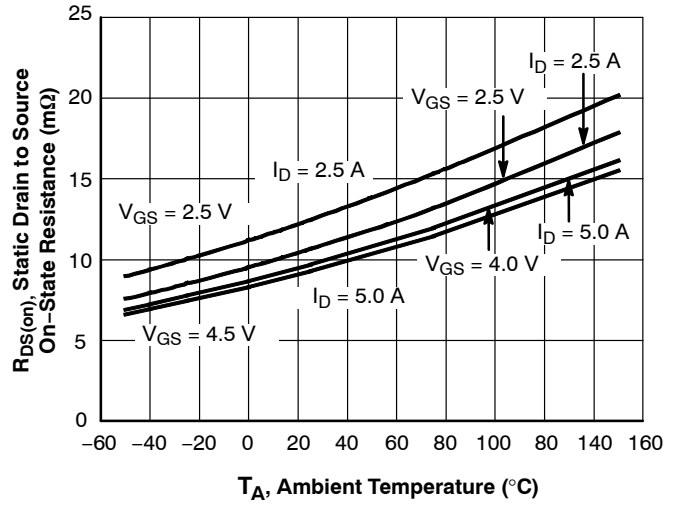


Figure 6. $R_{DS(on)} - T_A$

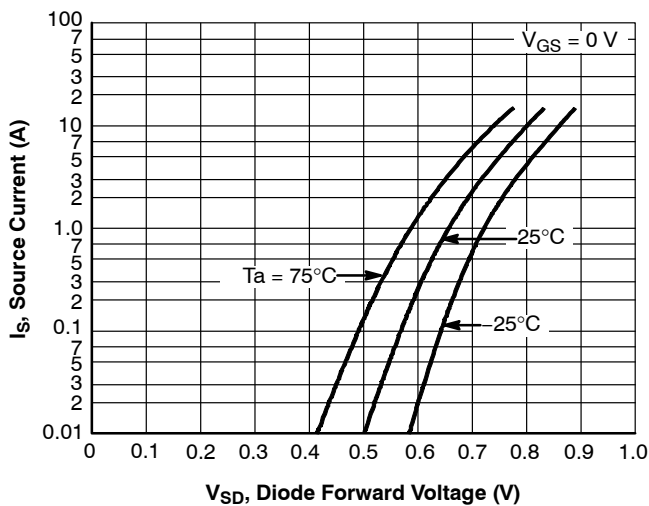


Figure 7. $I_S - V_{SD}$

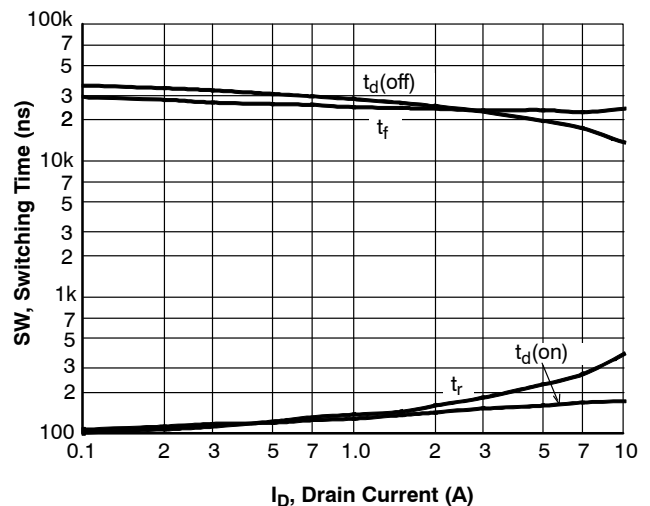
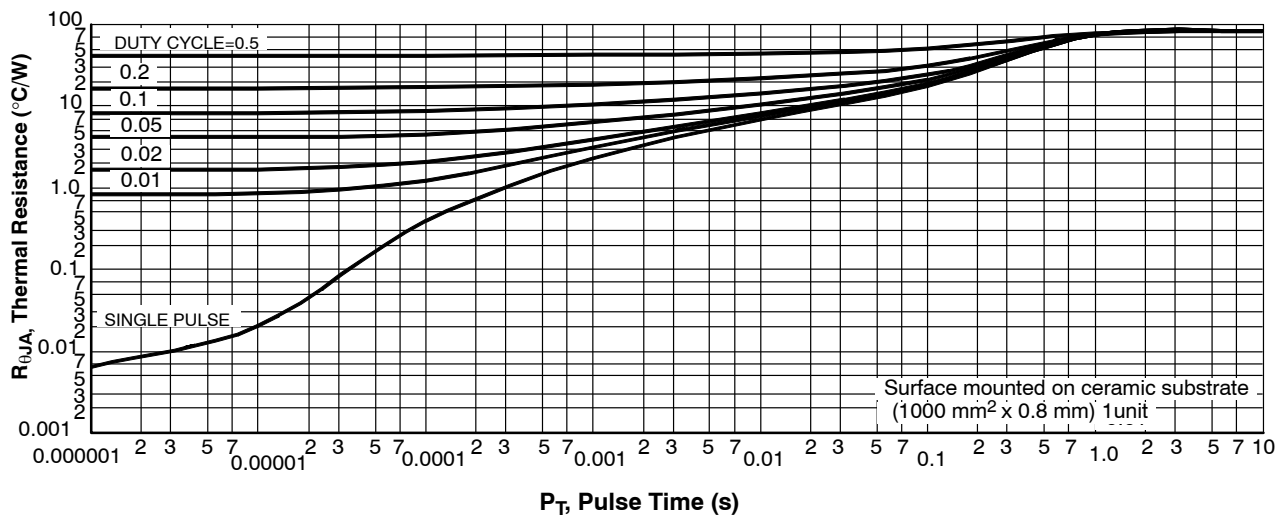
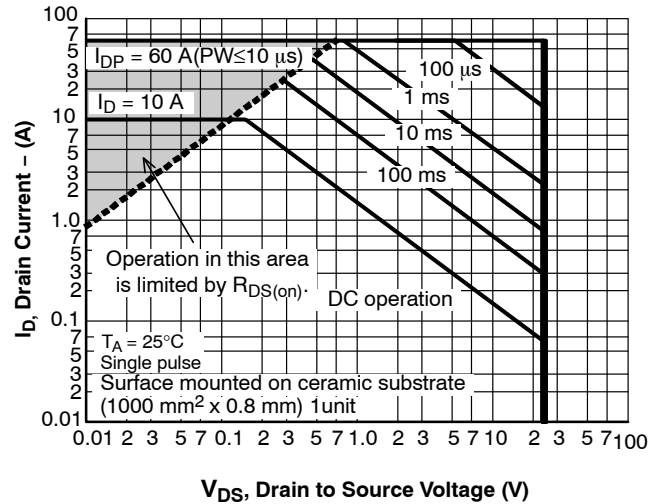
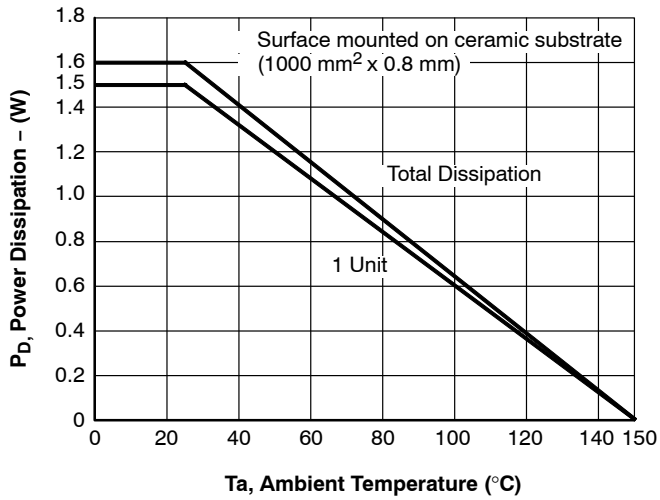
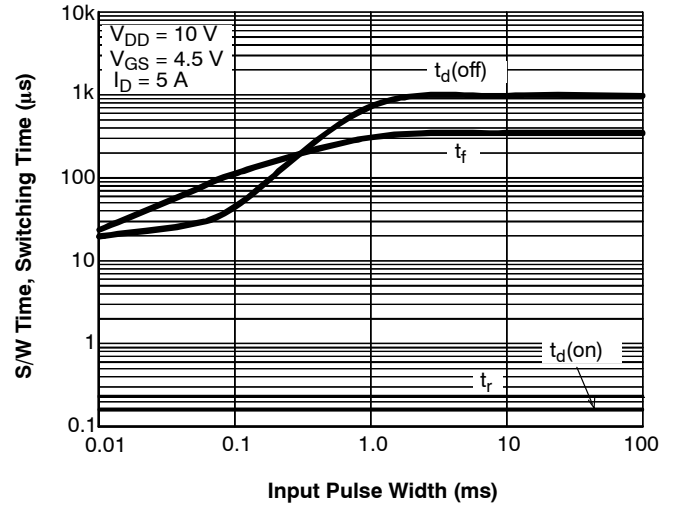
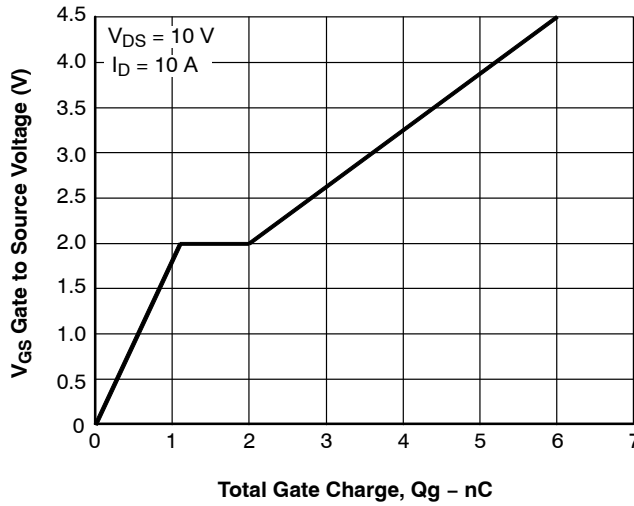


Figure 8. $I_D - \text{S/W Time}$

TYPICAL CHARACTERISTICS (CONTINUED)



ECH8697R

ORDERING INFORMATION

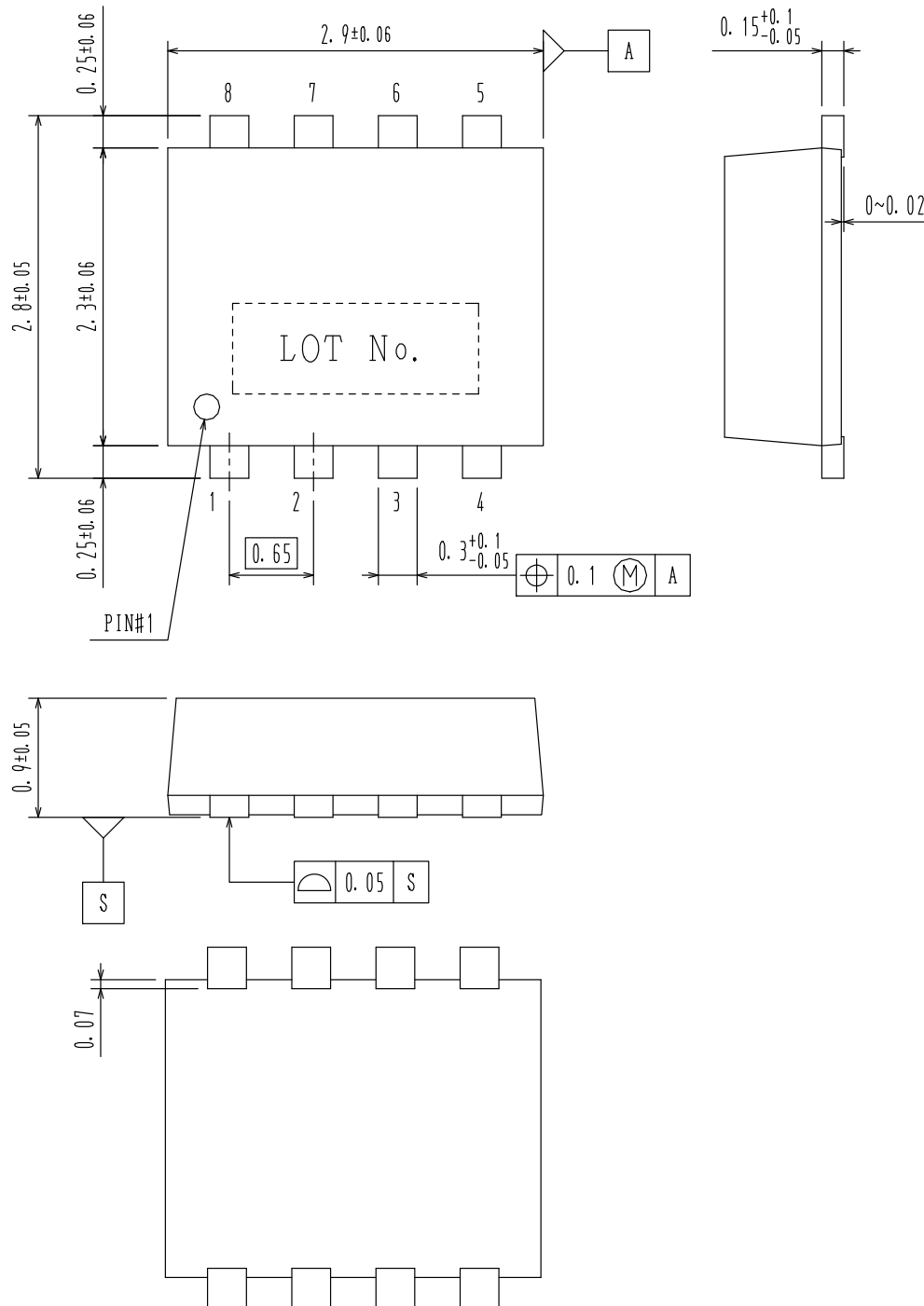
Product Number	Package	Shipping [†]
ECH8697R-TL-W	SOT-28FL, / ECH8 (Pb-Free / Halogen Free)	3000 / Tape and Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

Note on usage : Since the ECH8697R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects. Please contact sales for use except the designated application.

SOT-28FL / ECH8
CASE 318BF
ISSUE O

DATE 31 MAR 2012



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